## NSN 5962-01-444-9541

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View Online at https://aerobasegroup.com/nsn/5962-01-444-9541 **Body Length:** 0.458 inches **Body Width:** 0.458 inches **Body Height:** 0.180 inches **Maximum Power Dissipation Rating:** 1.5 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** F-15i **Features Provided:** Electrostatic sensitive and ultraviolet erasable and programmable and monolithic **Inclosure Material:** Silicon **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 24 input **Criticality Code Justification:** Cbbl **Case Outline Source And Designator:** D-15 mil-m-38510 **Terminal Surface Treatment:** Solder **Product Name:** Firmware, microcircuit, digital-programmable logic Voltage Rating And Type Per Characteristic: -2.0 volts total supply and 7.0 volts total supply **Memory Device Type:** Pal **Special Features:** Altered item; make from 5962-9061102yx, fielded software (pof file) version identification 8521164-101 **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 

28 printed circuit

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N/a

**Unit Of Measure:** 

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Demilitarization:

No

Fiig:

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